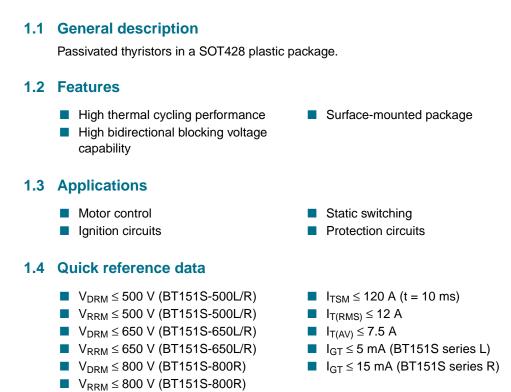


Thyristors Rev. 05 — 9 October 2006

Product data sheet

1. Product profile



2. Pinning information

| Table 1. | Pinning | | |
|----------|-----------------------------------|--------------------|-------------|
| Pin | Description | Simplified outline | Symbol |
| 1 | cathode (K) | | |
| 2 | anode (A) | mb | А₽К |
| 3 | gate (G) | | G sym037 |
| mb | mounting base; connected to anode | L | |
| | | | |
| | | | |
| | | SOT428 (DPAK) | |



Thyristors

3. Ordering information

| Table 2. Orderi | ng informatio | on | | | | | |
|-----------------|---------------|--|---------|--|--|--|--|
| Type number | Package | Package | | | | | |
| | Name | Description | Version | | | | |
| BT151S-500L | DPAK | plastic single-ended surface-mounted package; 3 leads (one lead cropped) | SOT428 | | | | |
| BT151S-500R | | | | | | | |
| BT151S-650L | | | | | | | |
| BT151S-650R | | | | | | | |
| BT151S-800R | | | | | | | |

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

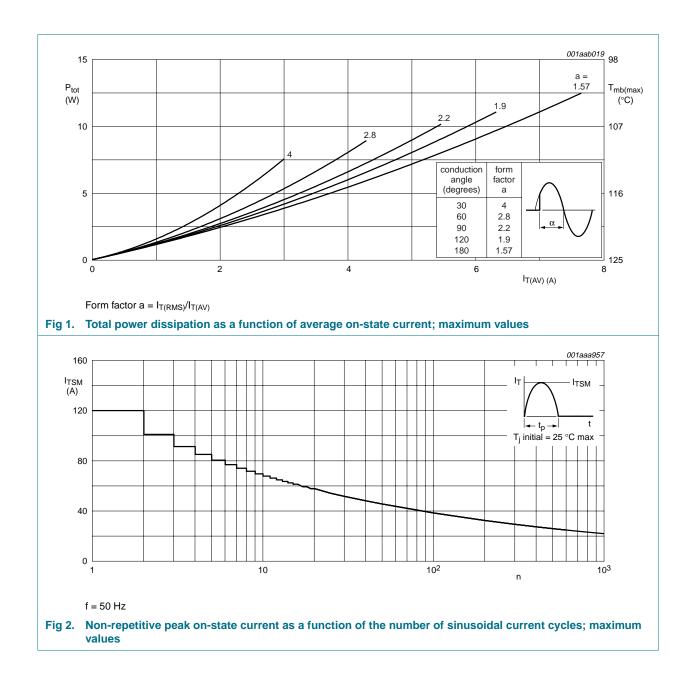
| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|--------------|------|------------------|
| V _{DRM} | repetitive peak off-state voltage | BT151S-500L; BT151S-500R | <u>[1]</u> _ | 500 | V |
| | | BT151S-650L; BT151S-650R | <u>[1]</u> - | 650 | V |
| | | BT151S-800R | - | 800 | V |
| V _{RRM} | repetitive peak reverse voltage | BT151S-500L; BT151S-500R | <u>[1]</u> _ | 500 | V |
| | | BT151S-650L; BT151S-650R | <u>[1]</u> _ | 650 | V |
| | | BT151S-800R | - | 800 | V |
| I _{T(AV)} | average on-state current | half sine wave; T _{mb} ≤ 103 °C; see <u>Figure 1</u> | - | 7.5 | А |
| I _{T(RMS)} | RMS on-state current | all conduction angles; see Figure 4 and $\frac{5}{2}$ | - | 12 | А |
| I _{TSM} | non-repetitive peak on-state current | half sine wave; $T_j = 25 \text{ °C}$ prior to surge; see Figure 2 and 3 | | | |
| | | t = 10 ms | - | 120 | А |
| | | t = 8.3 ms | - | 132 | А |
| l ² t | I ² t for fusing | t = 10 ms | - | 72 | A ² s |
| dl _T /dt | rate of rise of on-state current | I _{TM} = 20 A; I _G = 50 mA; dI _G /dt = 50 mA/μs | - | 50 | A/μs |
| I _{GM} | peak gate current | | - | 2 | А |
| V _{RGM} | peak reverse gate voltage | | - | 5 | V |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | +150 | °C |
| T _i | junction temperature | | - | 125 | °C |

 Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15A/µs.

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Product data sheet

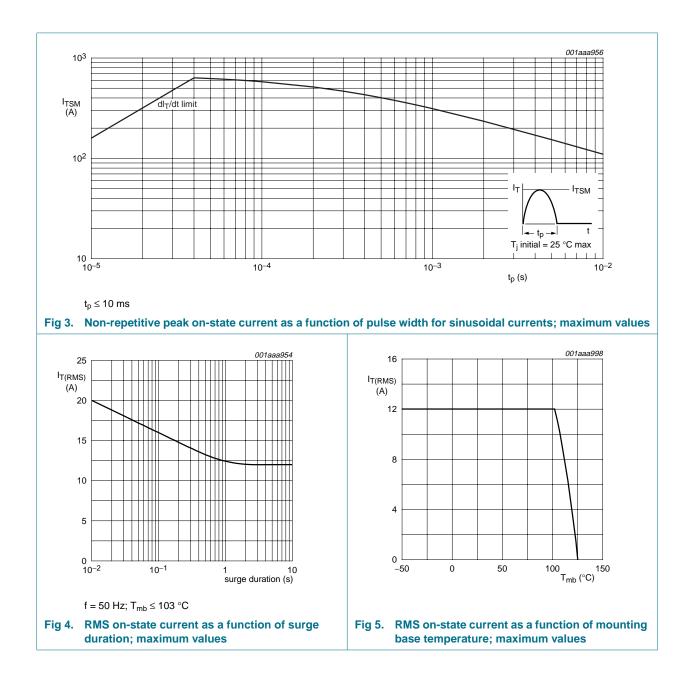
BT151S series L and R

Thyristors



BT151S series L and R

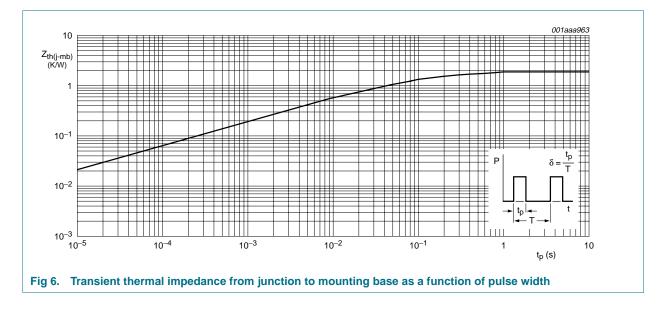
Thyristors



Thyristors

5. Thermal characteristics

| Table 4. | Thermal characteristics | | | | | | |
|-----------------------|---|---|-----|-----|-----|------|--|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | see <u>Figure 6</u> | - | - | 1.8 | K/W | |
| R _{th(j-a)} | thermal resistance from junction to ambient | mounted on an FR4 printed-circuit board; see <u>Figure 14</u> | - | 75 | - | K/W | |



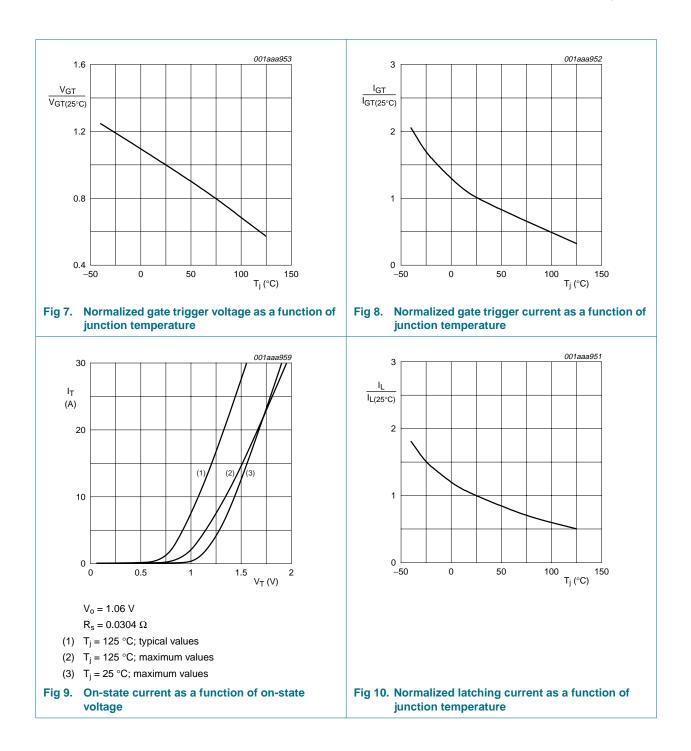
6. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|---|------|------|------|------|
| Static cha | racteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$ | | | | |
| | | BT151S-500L | - | 2 | 5 | mA |
| | | BT151S-500R | - | 2 | 15 | mA |
| | | BT151S-650L | - | 2 | 5 | mA |
| | | BT151S-650R | - | 2 | 15 | mA |
| | | BT151S-800R | - | 2 | 15 | mA |
| IL | latching current | V _D = 12 V; I _{GT} = 100 mA; see <u>Figure 10</u> | - | 10 | 40 | mA |
| I _H | holding current | V _D = 12 V; I _{GT} = 100 mA; see <u>Figure 11</u> | - | 7 | 20 | mA |
| V _T | on-state voltage | I _T = 23 A; see <u>Figure 9</u> | - | 1.4 | 1.75 | V |
| V _{GT} | gate trigger voltage | $I_T = 100 \text{ mA}; V_D = 12 \text{ V}; \text{ see } \frac{\text{Figure 7}}{\text{Figure 7}}$ | - | 0.6 | 1.5 | V |
| | | $ I_T = 100 \text{ mA}; V_D = V_{DRM(max)}; $ | 0.25 | 0.4 | - | V |
| I _D | off-state current | $V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$ | - | 0.1 | 0.5 | mA |
| I _R | reverse current | $V_R = V_{RRM(max)}; T_j = 125 \ ^{\circ}C$ | - | 0.1 | 0.5 | mA |
| Dynamic o | characteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | $V_{DM} = 0.67 \times V_{DRM(max)}$; $T_j = 125 \text{ °C}$; exponential waveform; see Figure 12 | | | | |
| | | R _{GK} = 100 Ω | 200 | 1000 | - | V/µs |
| | | gate open circuit | 50 | 130 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | $\begin{split} I_{TM} &= 40 \text{ A}; V_D = V_{DRM(max)}; \\ I_G &= 100 \text{ mA}; dI_G/dt = 5 A/\mu \text{s} \end{split}$ | - | 2 | - | μs |
| tq | commutated turn-off time | | - | 70 | - | μs |

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BT151S series L and R

Thyristors

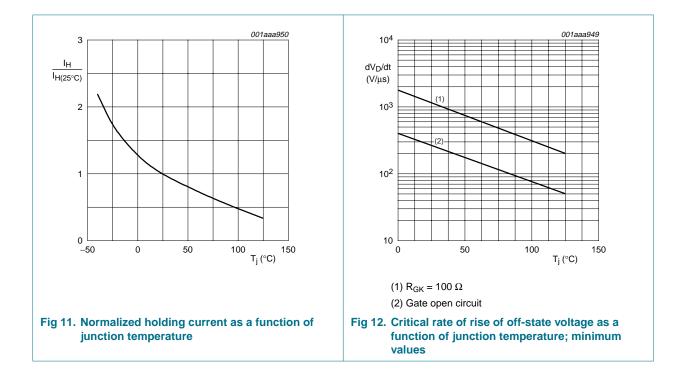


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Product data sheet

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BT151S series L and R

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Thyristors

7. Package outline

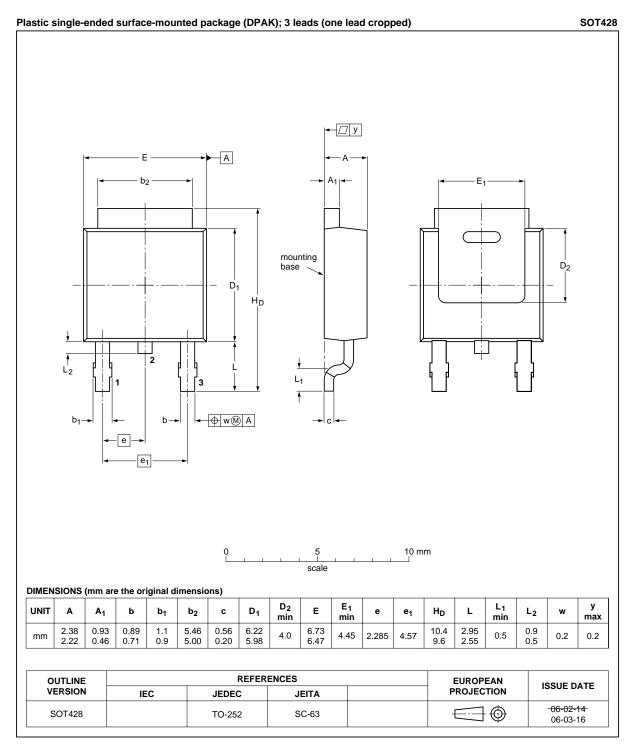


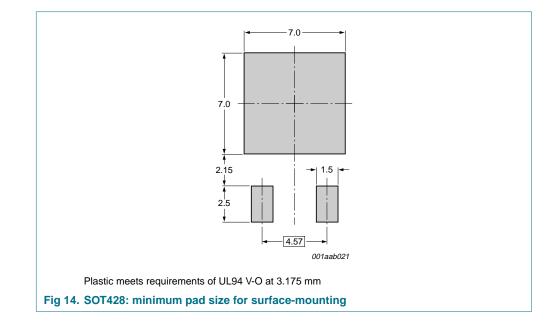
Fig 13. Package outline SOT428 (DPAK)

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Product data sheet

Thyristors

8. Mounting



BT151S_SER_L_R_5
Product data sheet

Thyristors

9. Revision history

| Table 6. Revision his | tory | | | | | |
|-------------------------------------|---|-----------------------------|--------------------|------------------|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
| BT151S_SER_L_R_5 | 20061009 | Product data sheet | - | BT151S_SERIES_4 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | | |
| | Legal texts | have been adapted to the ne | w company name whe | ere appropriate. | | |
| | Added type | numbers BT151S-500L and | BT151S-650L | | | |
| BT151S_SERIES_4 (9397 750 13161) | 20040609 | Product specification | - | BT151S_SERIES_3 | | |
| BT151S_SERIES_3 | 20020101 | Product specification | - | BT151S_SERIES_2 | | |
| BT151S_SERIES_2 | 19990601 | Product specification | - | BT151S_SERIES_1 | | |
| BT151S_SERIES_1 | 19970901 | Product specification | - | - | | |
| | | | | | | |

10. Legal information

10.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Date of release: 9 October 2006 Document identifier: BT151S_SER_L_R_5